# SKT 2400



Capsule Thyristor

Line	Thyristor
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#### SKT 2400

### Features

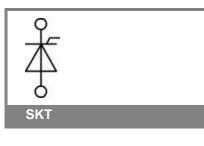
- Hermetic metal case with ceramic insulator
- Capsule package for double sided cooling
- Shallow design with single sided cooling
- Off-state and reverse voltages up to 1800 V
- Amplifying gate

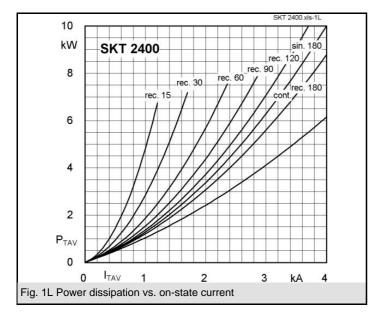
### **Typical Applications**

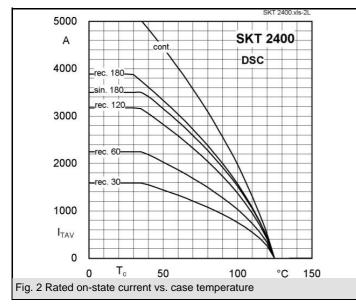
- DC motor control (e. g. for machine tools)
  Controlled rectifiers
- (e. g. for battery charging)
- AC controllers (e. g. for temperature control)
- Soft starters for AC motors
- Recommended snubber network e. g. for  $V_{VRMS} \leq 400$  V: R = 33  $\Omega/32$  W, C = 1  $\mu F$

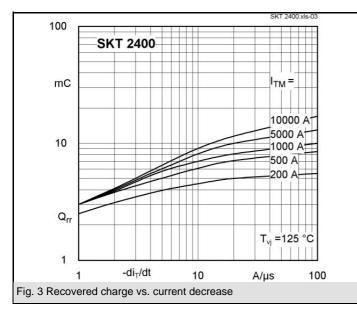
V <sub>RSM</sub>	V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>TRMS</sub> = 5700 A (maximum value for continuous operation)		
V	V	I <sub>TAV</sub> = 2400 A (sin. 180; DSC; T <sub>c</sub> = 76 °C)		
1300	1200	SKT 2400/12E		
1500	1400	SKT 2400/14E		
1700	1600	SKT 2400/16E		
1900	1800	SKT 2400/18E		

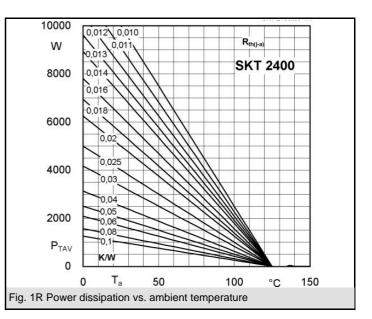
Symbol	Conditions	Values	Units
I <sub>TAV</sub>	sin. 180; T <sub>c</sub> = 100 (85) °C;	1520 (2100 )	А
I <sub>D</sub>	2 x N4/250; T <sub>a</sub> = 45 °C; B2 / B6	2650 / 3700	А
I <sub>RMS</sub>	2 x N4/250; T <sub>a</sub> = 45 °C; W1C	3000	А
I <sub>TSM</sub>	T <sub>vi</sub> = 25 °C; 10 ms	55000	Α
	T <sub>vj</sub> = 125 °C; 10 ms	47000	А
i²t	T <sub>vj</sub> = 25 °C; 8,3 10 ms	15125000	A²s
	T <sub>vj</sub> = 125 °C; 8,3 10 ms	11000000	A²s
V <sub>T</sub>	T <sub>vj</sub> = 25 °C; I <sub>T</sub> = 3000 A	max. 1,37	V
V <sub>T(TO)</sub>	T <sub>vi</sub> = 125 °C	max. 0,88	V
r <sub>T</sub>	T <sub>vj</sub> = 125 °C	max. 0,164	mΩ
I <sub>DD</sub> ; I <sub>RD</sub>	$T_{vj}$ = 125 °C; $V_{RD}$ = $V_{RRM}$ ; $V_{DD}$ = $V_{DRM}$	max. 100	mA
t <sub>gd</sub>	T <sub>vj</sub> = 25 °C; I <sub>G</sub> = 1 A; di <sub>G</sub> /dt = 1 A/µs	1	μs
t <sub>gr</sub>	V <sub>D</sub> = 0,67 * V <sub>DRM</sub>	2	μs
(di/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C	max. 150	A/µs
(dv/dt) <sub>cr</sub>	T <sub>vi</sub> = 125 °C	max. 1000	V/µs
t <sub>q</sub>	T <sub>vi</sub> = 125 °C ,	200 300	μs
I <sub>H</sub>	T <sub>vj</sub> = 25 °C; typ. / max.	500 / 1000	mA
I <sub>L</sub>	T <sub>vj</sub> = 25 °C; typ. / max.	2000 / 5000	mA
V <sub>GT</sub>	T <sub>vi</sub> = 25 °C; d.c.	min. 3	V
I <sub>GT</sub>	$T_{vj} = 25 \text{ °C}; \text{ d.c.}$	min. 300	mA
V <sub>GD</sub>	T <sub>vj</sub> = 125 °C; d.c.	max. 0,25	V
I <sub>GD</sub>	T <sub>vj</sub> = 125 °C; d.c.	max. 10	mA
R <sub>th(j-c)</sub>	cont.; DSC	0,0105	K/W
R <sub>th(j-c)</sub>	sin. 180; DSC / SSC	0,011 / 0,024	K/W
R <sub>th(j-c)</sub>	rec. 120; DSC / SSC	0,0118 / 0,025	K/W
R <sub>th(c-s)</sub>	DSC / SSC	0,002 / 0,004	K/W
T <sub>vj</sub>		- 40 + 125	°C
T <sub>stg</sub>		- 40 + 130	°C
V <sub>isol</sub>		-	٧~
F	mounting force	37 47	kN
а			m/s²
m	approx.	1000	g
Case		B 20	
		1	

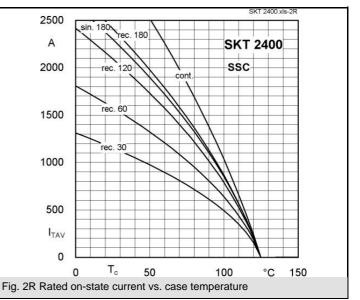


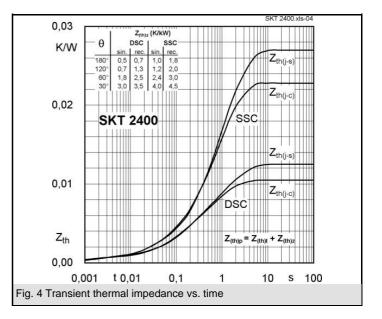




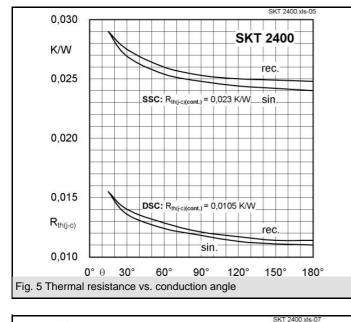


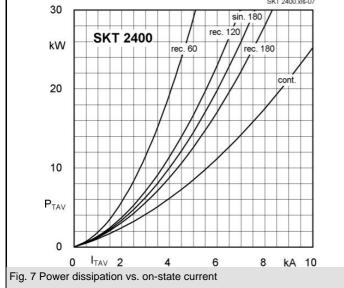


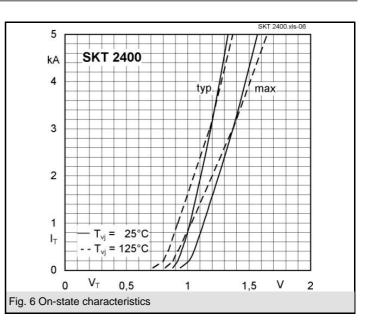


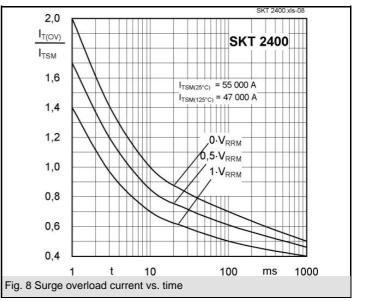


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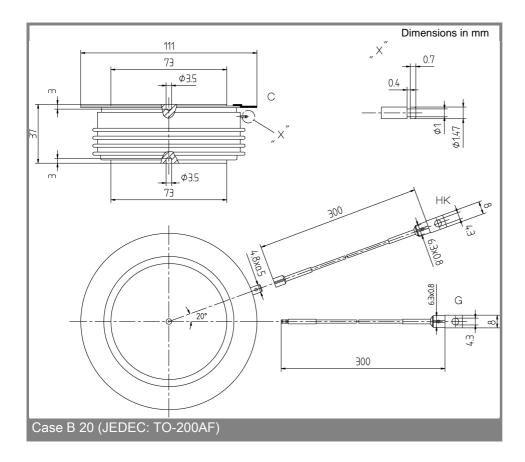








SKT 2400.xls-09 100 SKT 2400 V 20V; 10Ω 10 20W (0,1 VGT BSZ -40°0 1 = 25°C 125°C. BMZ P<sub>G</sub>(t<sub>p</sub>) V<sub>GD(125°)</sub>  $V_{\rm G}$ GT IGD(125°) 0,1  $I_{G}$ 0,001 0,01 0,1 1 10 A 100 Fig. 9 Gate trigger characteristics



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